



Modelling charge generation and transport in solid organic dielectrics under DC stress

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Overview

- Context
- Existing types of models in solid dielectrics
- Intermediate models:
 - Identification of physical hypotheses
 - Space charge in a cable geometry: simulation results



Polymeric HVDC technology

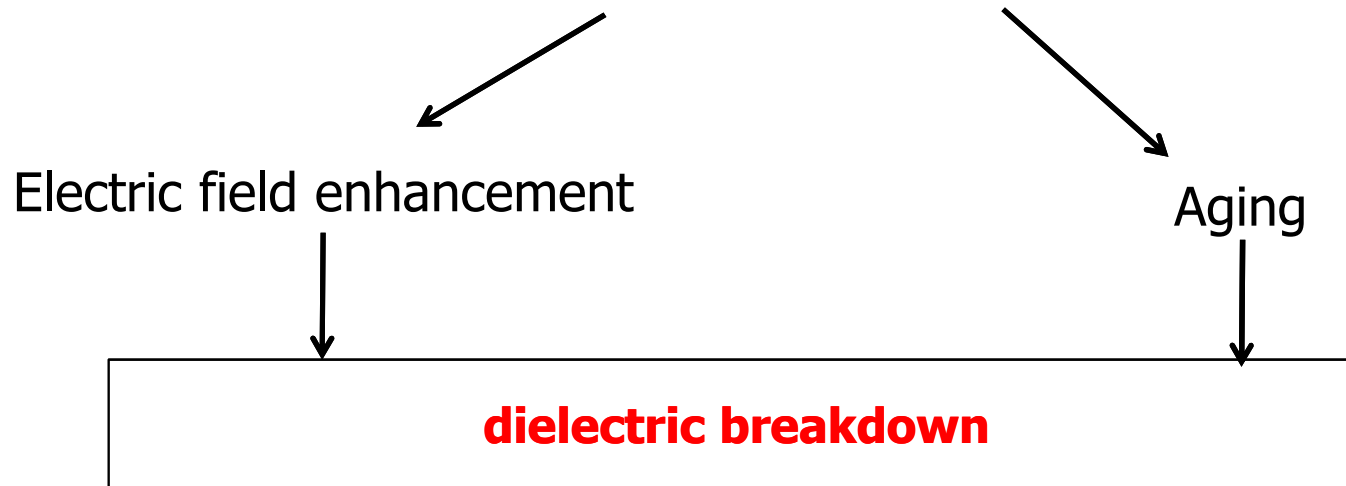
- XLPE as electrical insulation for HVDC transmissions
 - HVDC LCC
 - HVDC VSC
- ADVANTAGES OF HVDC:
 - Transport of electricity over long distances
 - Link with networks of different frequencies
- HVDC APPLICATIONS

 RELIABILITY

Industrial Background

RELIABILITY ?

Problem: presence of electrical charges



MODELS

To understand the causes and consequences of the presence of charges in solid dielectrics



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Existing models in solid dielectrics

o **Microscopic models:**

- + energy levels linked to chemical or physical defects
- + Density Functional Theory (DFT) calculations – quantum mechanical computations

😊 rigorous description

☹ high calculation time

☹ no prediction of the macroscopic characteristics

o **Macroscopic models:**

- + conductivity / permittivity as a function of field and temperature
- + based on experiments

o **Semi-microscopic – Intermediate - models:**

- + transport phenomena
- + microscopic phenomena with effective parameters



Examples of results from microscopic models

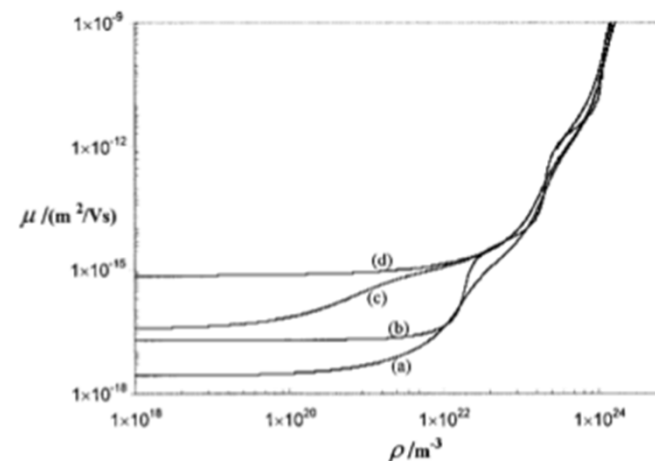
M. Meunier, N. Quirke, et al

Calculation of the trap depth as a function of the chemical impurities in XLPE [1]

Molecule	Electron affinity	Trap depth
(a) decane ($n\text{-C}_{10}\text{H}_{22}$)	-1.366 ^a	0
(b) 5-decanone ($\text{C}_{10}\text{H}_{20}\text{O}$)	-0.913	0.453
(c) 5-decene ($\text{C}_{10}\text{H}_{20}$)	-1.244	0.122
(d) 4,6-decene ($\text{C}_{10}\text{H}_{18}$)	-0.923	0.443
(e) 5-decyne ($\text{C}_{10}\text{H}_{18}$)	-1.325	0.041
(f) 5-vinyl nonane ($\text{C}_{10}\text{H}_{20}$)	-1.209	0.157
(g) 5-decanol ($\text{C}_{10}\text{H}_{21}\text{O}$)	-1.180	0.186
(h) 5-decanal ($\text{C}_{10}\text{H}_{20}\text{O}$)	-0.921	0.445
(i) 4-propyl heptane ($\text{C}_{10}\text{H}_{22}$)	-1.245	0.121
(j) alpha-methylstyrene, C_9H_{10}	0.23	1.53
(k) Cumylalcohol, $\text{C}_9\text{H}_{12}\text{O}$	-1.02	0.28
(l) Acetophenone, $\text{C}_8\text{H}_8\text{O}$	-0.40	0.90
(m) Cumene, C_9H_{12}	-1.26	0.04

^aReference 19.

Modelling the charge mobility and the J-E curves from trap distributions [2]

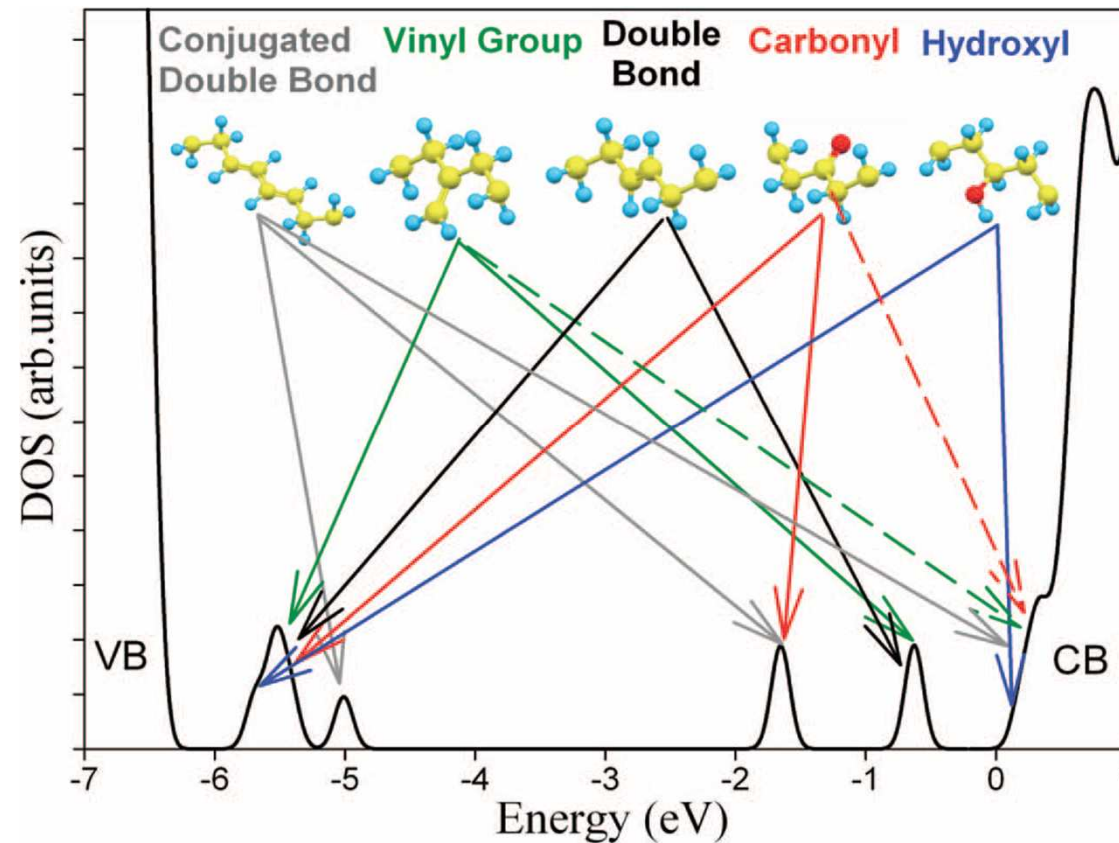


[1] M. Meunier, N. Quirke, and A. Aslanides, Journal of Chem. Phys. **115**, pp. 2876-2881 (2001)

[2] J. A. Anta, G. Marcelli, M. Meunier, and N. Quirke, J. of Appl. Phys. **92**, 1002 (2002)

Examples of results from microscopic models

Hussayyin et al [3]

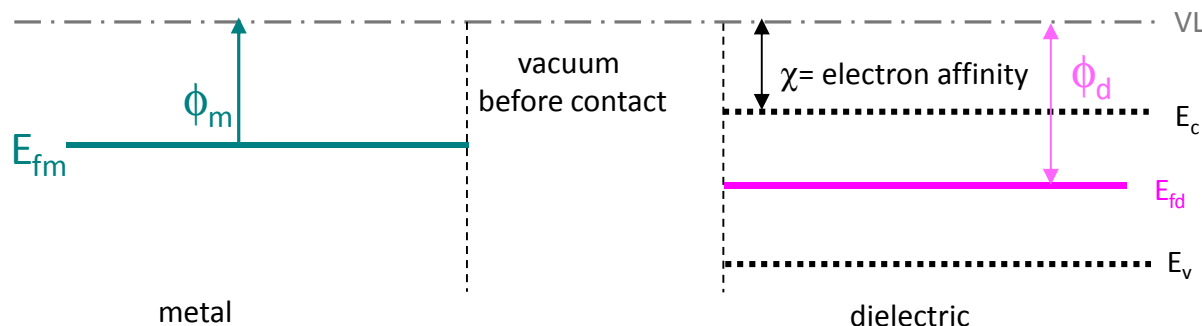




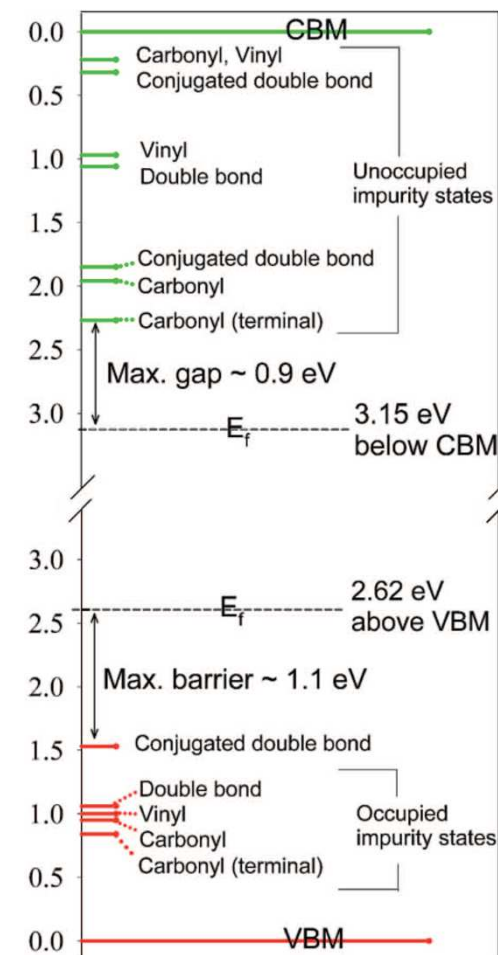
Examples of results from microscopic models

Hussayyin et al [3]

Understanding the metal/PE interface



For Pt/PE interface





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o **Macroscopic models:**

- + conductivity / permittivity as a function of field and temperature
- + based on experiments

😊 macroscopic characteristics

☹ no prediction of space charge behaviour

😊 description of complex systems

☹ no access to transient mechanisms

o **Semi-microscopic – Intermediate - models:**

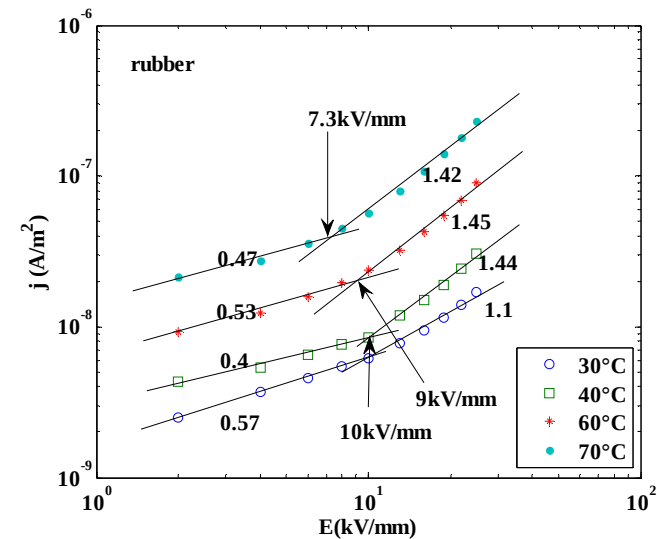
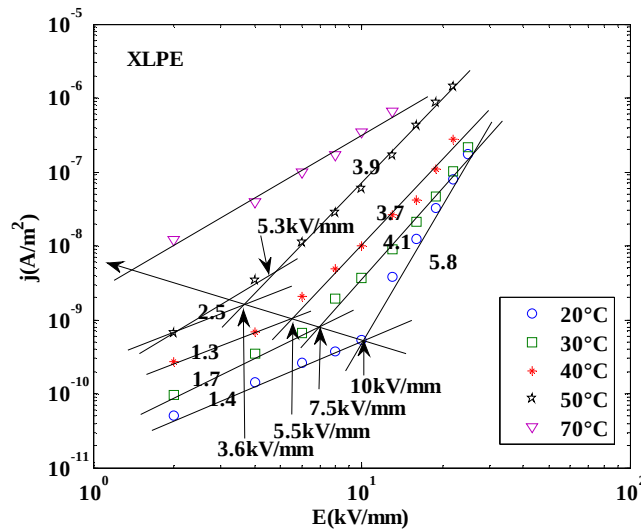
- + transport phenomena
- + microscopic phenomena with effective parameters



Examples of results from macroscopic models

Vu et al [4]

1. Current measurements function of field and temperature



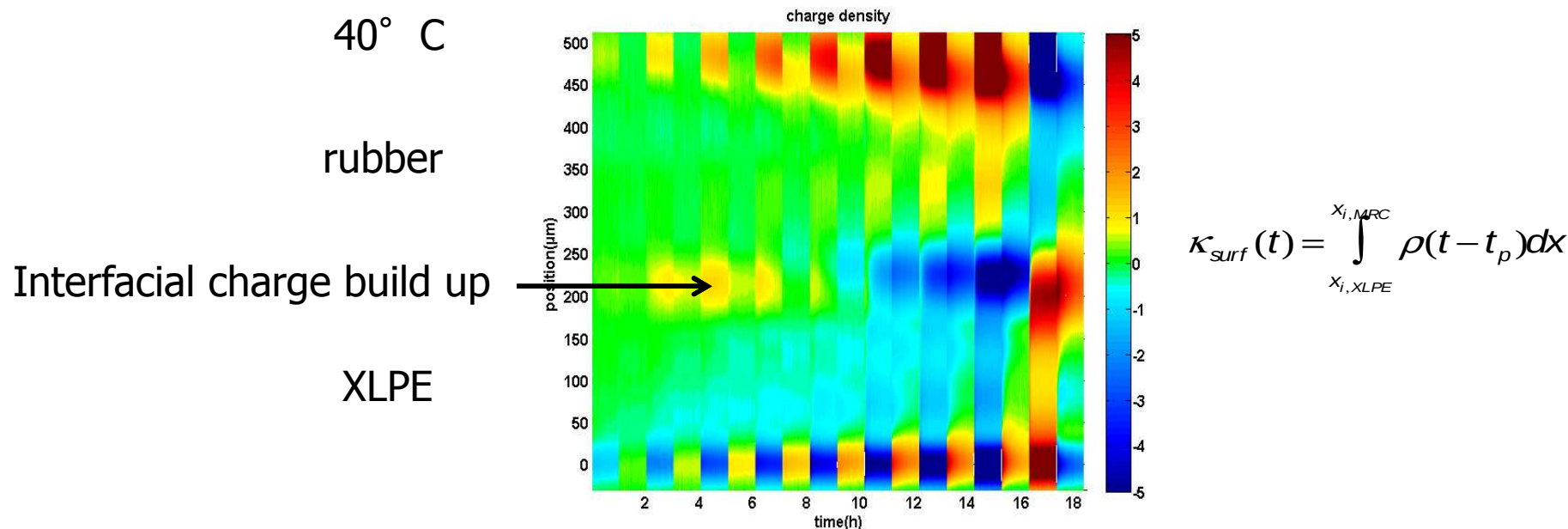
[4] T.T.N. Vu, G. Teyssedre, B. Vissouvanadin, S. Le Roy, C. Laurent, M. Mammeri, and I. Denizet, *Proceedings of the International Conference on Solid Dielectrics (ICSD)*, p. 413-416, 2013



Examples of results from macroscopic models

Vu et al [4]

1. Current measurements function of field and temperature
2. Space charge measurements on rubber/PE sandwiches



[4] T.T.N. Vu, G. Teyssedre, B. Vissouvanadin, S. Le Roy, C. Laurent, M. Mammeri, and I. Denizet, *Proceedings of the International Conference on Solid Dielectrics (ICSD)*, p. 413-416, 2013

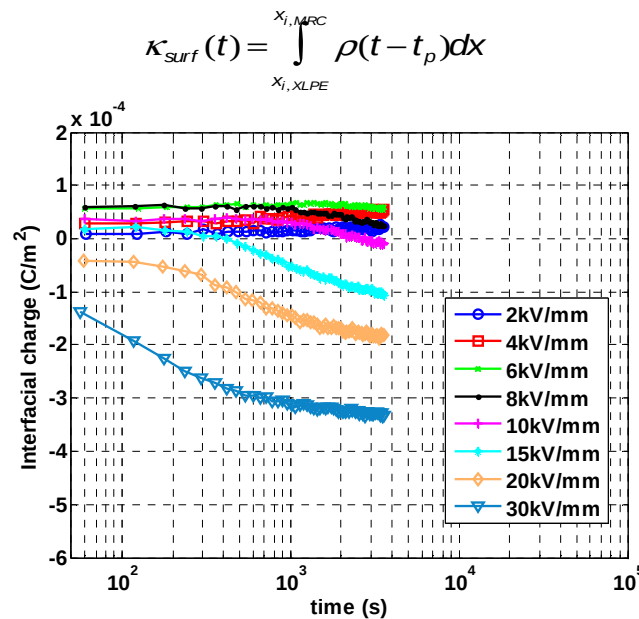


Examples of results from macroscopic models

Vu et al [4]

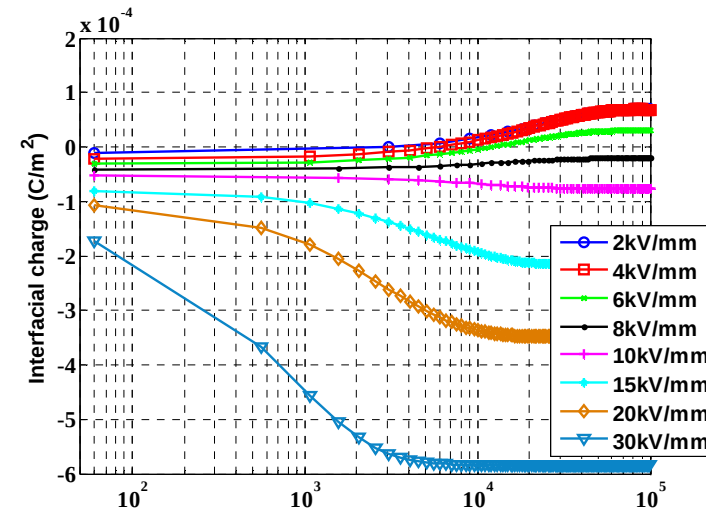
1. Current measurements function of field and temperature
2. Space charge measurements on rubber/PE sandwiches
3. Evaluation of the interface charge

From experiment



From simulation

$$\sigma(T,E) = A \cdot \exp\left(\frac{-E_a}{k_B T}\right) \cdot \sinh(B(T) \cdot E) \cdot E^\alpha$$



[4] T.T.N. Vu, G. Teyssedre, B. Vissouvanadin, S. Le Roy, C. Laurent, M. Mammeri, and I. Denizet, *Proceedings of the International Conference on Solid Dielectrics (ICSD)*, p. 413-416, 2013



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- + microscopic phenomena with effective parameters

😊 macroscopic characteristics

😊 transient phenomena / space charge

☹️ difficult parameterization



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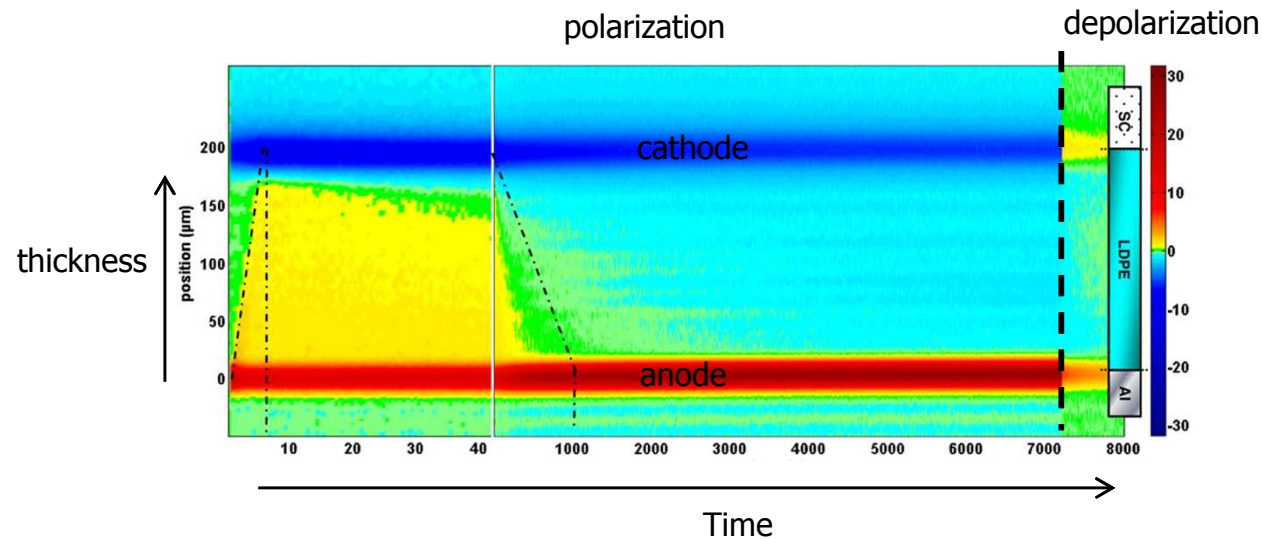


Identification of physical hypotheses

Space charge measurement using the Pulsed Electro-Acoustic method (PEA) [5]

LDPE (low density polyethylene) 200 μm

Applied field -30 kV/mm – polarization 2h – $T=40^\circ\text{C}$



Identification of physical mechanisms:

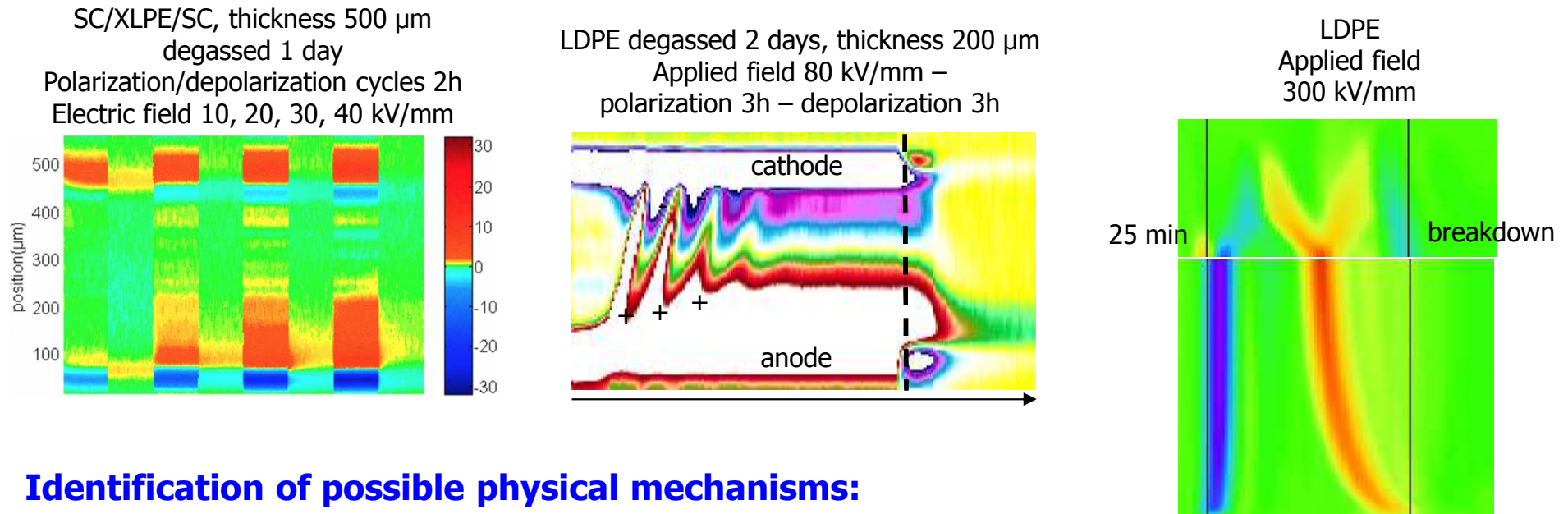
- o Injection of positive charges at the anode, negative charges at the cathode
- o Transport through the dielectric

[5] Thomas et al, J. Phys. D: Appl. Phys. 44 (2011) 015401



Identification of physical hypotheses

Space charge measurements using the Pulsed Electro-Acoustic method (PEA) [6,7,8]



Identification of possible physical mechanisms:

- o Electronic charge injection and transport ?
- o Small transit time -> fast positive charge transport? Or other type of carrier?
- o Ionisation? or dissociation?
- o Extraction barrier?
- o Repetition of the packet initialization at the electrode or surface inhomogeneity ?(initialization of fronts of charge at different point of the surface, integrated with the measurement method)
- o ...

[6] Vissouvanadin B. et al, ICPADM 2009, Harbin, China, pp 961-964, 2009

[7] Montanari et al, unpublished results

[8] Matsui K. et al, IEEE Trans. Dielectr. Electr. Insul., 12, 406-415, 2005



Charge generation

Hypothesis: Dielectric sandwiched between two electrodes

➔ injection of charges from electrodes

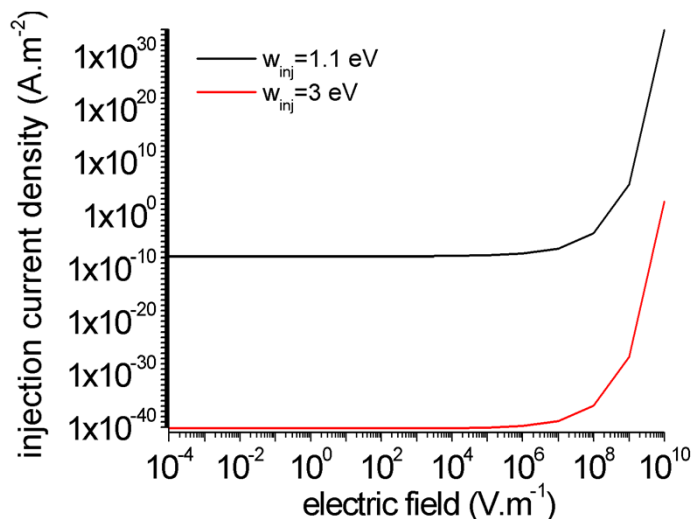
Fowler-Nordheim Emission=
field emission – quantum-mechanical tunnelling

$$j_{F-N} = \frac{e^3 E^2}{8\pi h \phi} \exp \left[-\frac{4}{3} \left(\frac{2m}{\hbar^2} \right)^{\frac{1}{2}} \frac{\phi^{\frac{3}{2}}}{eE} \right]$$

Schottky injection
= thermionic emission

$$j_s = A T^2 \exp \left(-\frac{e\phi_B}{k_B T} \right) \left(\exp \left(\frac{e}{k_B T(t)} \sqrt{\frac{eE_{electrode}}{4\pi\epsilon_0\epsilon_r}} \right) \right)$$

ϕ_B barrier height



example interface Au/PE $\phi_{theoretical} > 4\text{eV}$

Impossible to take into account theoretical barrier height values.

For a small or zero electric field, there is always an injection due to the thermal effect.



Charge generation at interfaces

- o Schottky equation used with lower values of the injection barrier height (~ 1 eV)
- o Ohm's law also used
- o Development of injection 'laws' improving the injection description:
 - ✓ Modified Schottky (no injection when $E_a=0$)

$$j_S = AT^2 \exp\left(-\frac{W_{e,h}}{k_B T}\right) \left(\exp\left(\frac{e}{k_B T(t)} \sqrt{\frac{eE_{electrode}}{4\pi\epsilon_0\epsilon_r}}\right) - 1 \right)$$

- ✓ Injection according to a functional approximation for the current density [9]

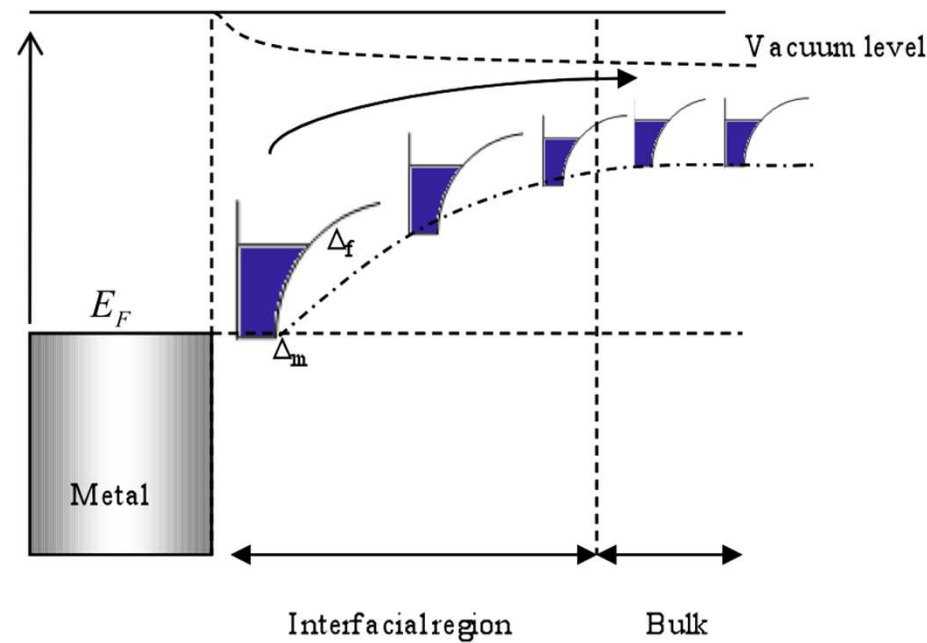
$$j_{e,h}(x,t) = \alpha \exp(\beta E(x,t))$$

[9] Hare R W, "Modelling space charge in solid dielectrics" *Ph.D. Thesis*, University of Bristol, 1993



Charge generation at interfaces

- o Microscopic description of the interface (higher density of states, deeper traps ..)
[10,11]



[10] Junfeng Xia et al, J. Appl. Phys., 109, 034101, 2011

[11] Taleb M et al, IEEE TDEI 2013

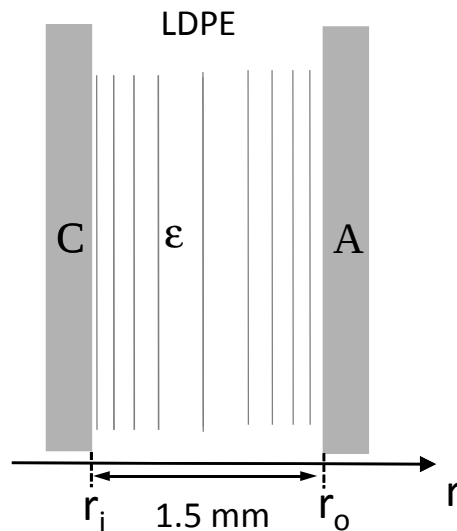
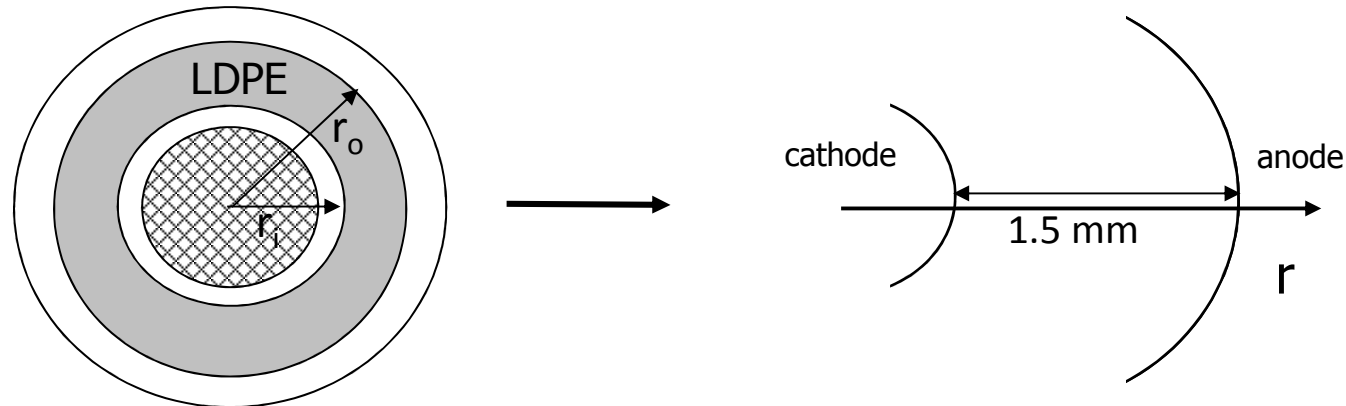


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Modelling charge transport in a cable



Experimental and simulation protocol

Mini-cable:

$$r_i = 1,4 \text{ mm}$$

$$r_o = 2,9 \text{ mm}$$

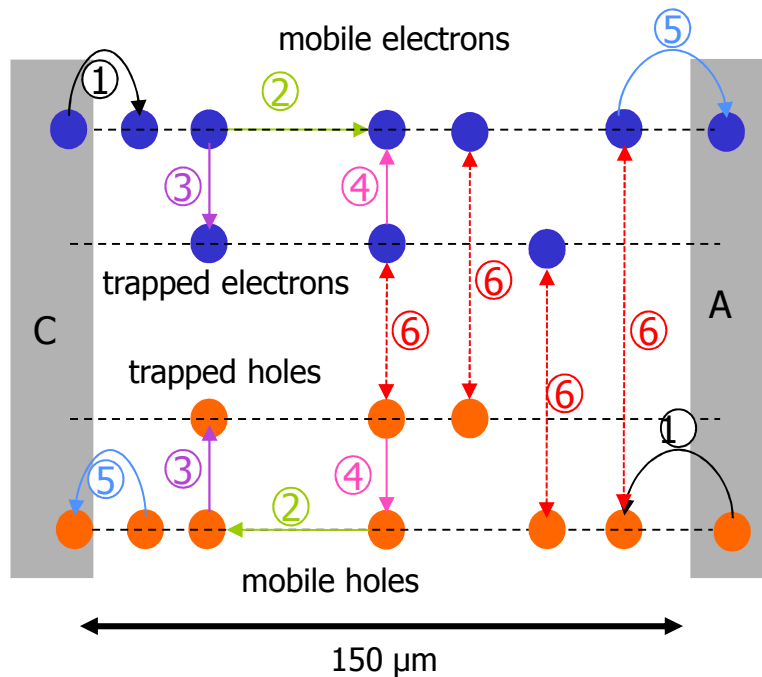
$$d = 1,5 \text{ mm}$$

$V = -30 \text{ kV}$ at the cathode

Polarization time: 4h



Physical hypotheses



- ① **Generation of carrier**
injection at each electrode, modified-Schottky law:

$$j_{e,h} = AT^2 \exp\left(-\frac{w_{e,h}}{k_B T}\right) \left(\exp\left(\frac{e}{k_B T} \sqrt{\frac{eE_{electrode}}{4\pi\epsilon_0\epsilon_r}}\right) - 1 \right)$$

- ② **Transport:** hopping mobility taking into account the trapping and detrapping of carriers into shallow traps

- ③ **Trapping:** carriers can be trapped into deep traps, using a trapping coefficient B_e and B_h

- ④ **Detrapping:** carriers have a detrapping probability function of an activation energy for electrons, for example:

$$D_e = \nu \exp\left(\frac{-W_{detrapp}}{k_B T}\right)$$

- ⑤ **Extraction:**
the extraction flux of carriers at each electrode is function of the field, for electrons at the anode for example:

$$j_{e,h}(electrode, t) = n_{e,h} \mu_{e,h} E(electrode, t)$$

- ⑥ **Recombination:**
Each kind of carrier can recombine with a carrier of opposite polarity, mobile or trapped, using a recombination parameter S_0 to S_3



Models of charge transport: equations to solve

- Poisson equation:
$$\frac{1}{r} \frac{\partial}{\partial r} \left(r \frac{\partial V(r)}{\partial r} \right) = - \frac{\rho(r, t)}{\epsilon}$$

ρ : net charge density (C.m⁻³)

ϵ : permittivity

V : voltage (V.m⁻¹)

- Continuity equation:
$$\frac{\partial n_a(r, t)}{\partial t} + \frac{1}{r} \frac{\partial j_a(r, t)}{\partial r} = s_a(r, t)$$

n_a : charge density (C.m⁻³)

j_a : flux density (A.m⁻²)

s_a : source term (C.m⁻³.s⁻¹)

- Transport equation:
$$j_a(r, t) = n_a(r, t) \mu_a(r, t) E(r, t)$$

E : electric field (V.m⁻¹)

μ : mobility (m².V⁻¹.s⁻¹)

- Hopping mobility:
$$\mu_{e,h}(r, t) = \frac{2vd}{E(r, t)} \exp \left(\frac{-e w_{\mu e, \mu h}}{k_B T(r)} \right) \sinh \left(\frac{e E(r, t) d}{2 k_B T(r)} \right)$$

v : attempt to escape frequency (s⁻¹)

d : distance between traps (m)

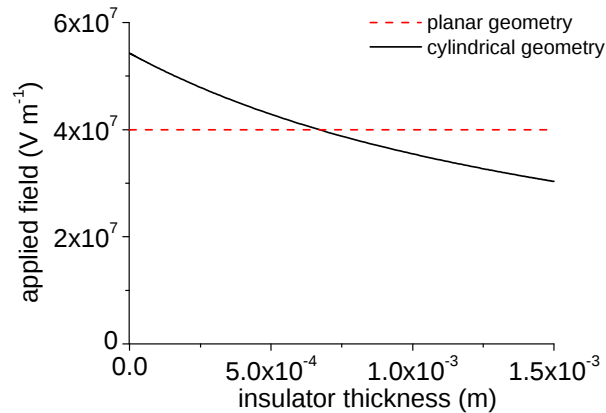
k_B : Boltzmann constant (J.K⁻¹)

$w_{\mu e, \mu h}$: trap depth (eV)

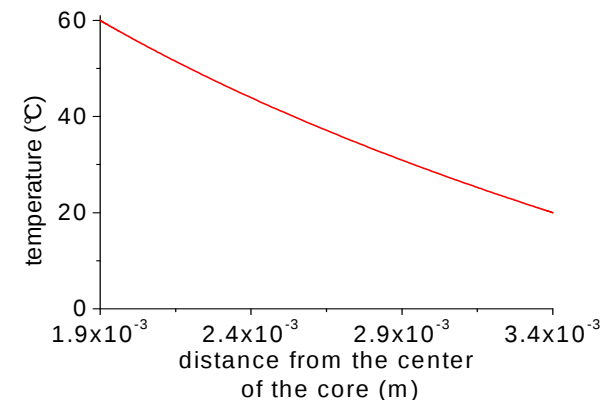


What does a cylindrical geometry imply ?

- Non uniformity of the applied field



- Application of a current in the core of the cable → temperature gradient



$$T(r) = T(r_{in}) - \frac{\ln\left(\frac{r}{r_{in}}\right)(T(r_{in}) - T(r_{out}))}{\ln\left(\frac{r_{out}}{r_{in}}\right)}$$

Effect on injection

$$j_{e,h} = AT^2 \exp\left(-\frac{w_{e,h}}{k_B T}\right) \left(\exp\left(\frac{e}{k_B T} \sqrt{\frac{eE_{electrode}}{4\pi\epsilon_0\epsilon_r}}\right) - 1 \right)$$

Effect on mobility

$$\mu_{e,h}(r,t) = \frac{2vd}{E(r,t)} \exp\left(\frac{-ew_{\mu e, \mu h}}{k_B T(r)}\right) \sinh\left(\frac{eE(r,t)d}{2k_B T(r)}\right)$$



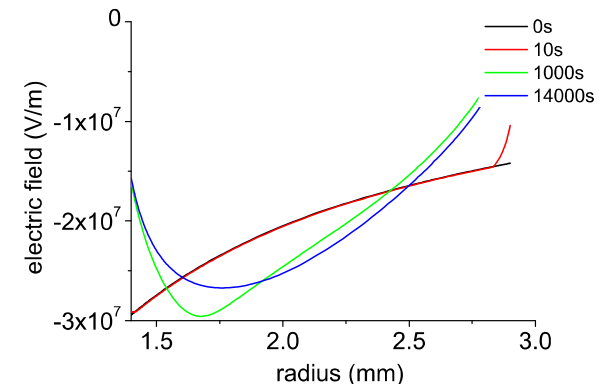
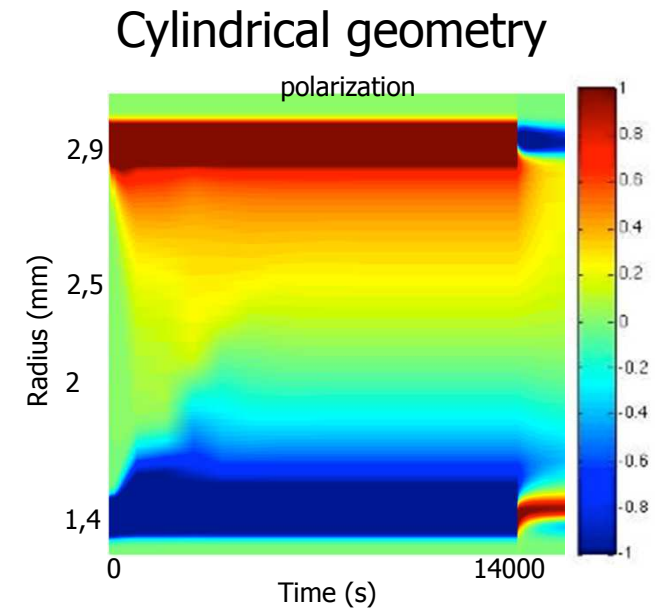
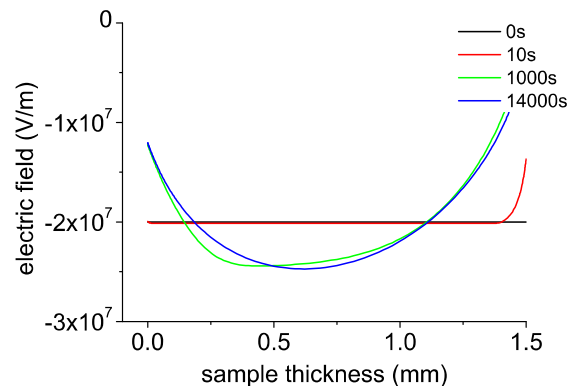
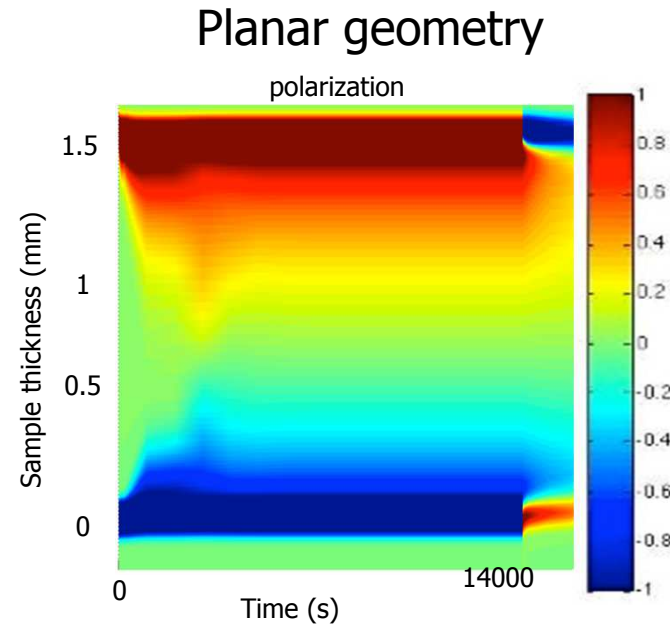
Model parameters

Symbol	value	units
recombination coefficients		
S_0 trapped electron/trapped hole	$4 \cdot 10^{-3}$	$\text{m}^3 \cdot \text{C}^{-1} \cdot \text{s}^{-1}$
S_1 mobile electron/trapped hole	$4 \cdot 10^{-3}$	$\text{m}^3 \cdot \text{C}^{-1} \cdot \text{s}^{-1}$
S_2 trapped electron/mobile hole	$4 \cdot 10^{-3}$	$\text{m}^3 \cdot \text{C}^{-1} \cdot \text{s}^{-1}$
S_3 mobile electron/mobile hole	0	$\text{m}^3 \cdot \text{C}^{-1} \cdot \text{s}^{-1}$
trapping coefficients		
B_e electrons	$1 \cdot 10^{-1}$	s^{-1}
B_h holes	$2 \cdot 10^{-1}$	s^{-1}
Trap depths (hopping mobility)		
electrons	0.71	eV
holes	0.65	eV
trap densities		
n_{oet} for electrons	100	$\text{C} \cdot \text{m}^{-3}$
n_{oht} for holes	100	$\text{C} \cdot \text{m}^{-3}$
injection barrier heights		
w_{ei} for electrons	1.27	eV
w_{hi} for holes	1.16	eV
Detrapping barrier heights		
w_{tre} for electrons	0.96	eV
w_{trh} for holes	0.99	eV



Simulation results: geometry dependence

Comparison between planar and cylindrical space charge profiles at $T=60^\circ\text{C}$, $V=-30\text{kV}$

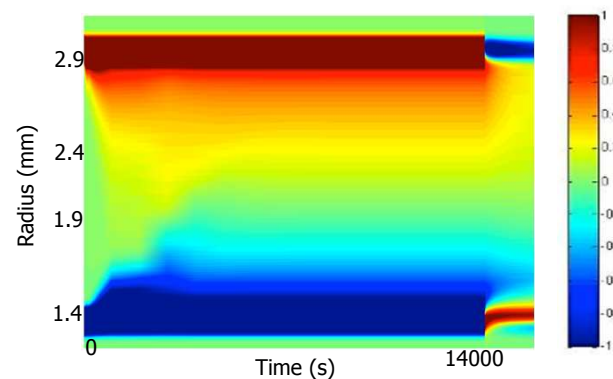




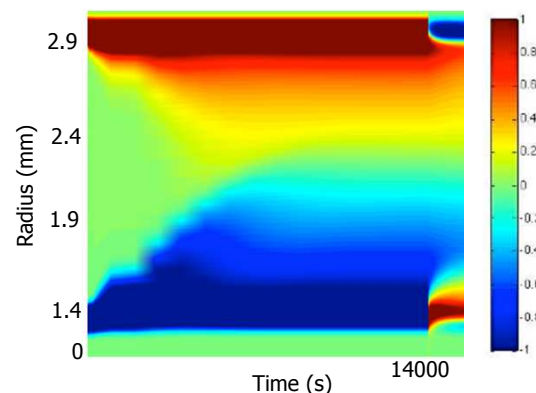
Simulation results: temperature gradients

Comparison between cylindrical space charge profiles for $V = -30\text{kV}$, $T_{in} = 60^\circ\text{C}$

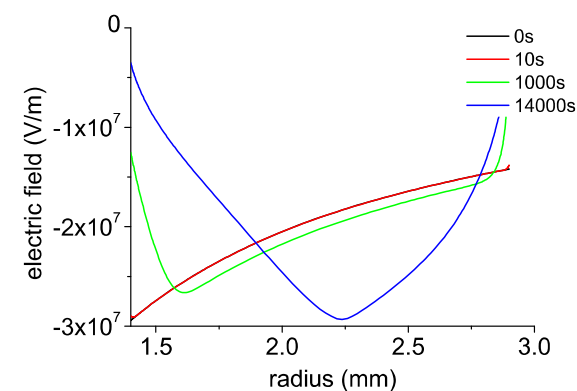
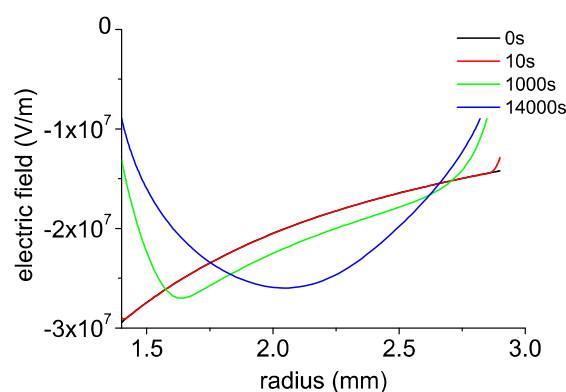
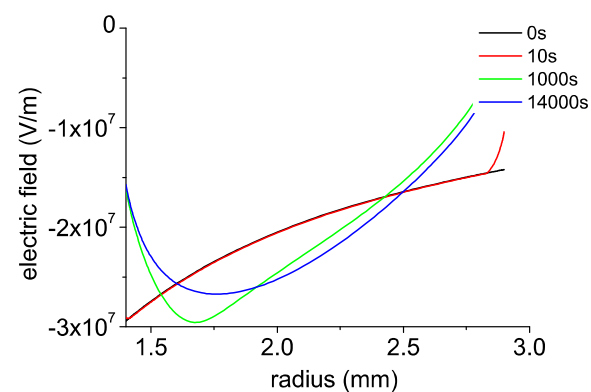
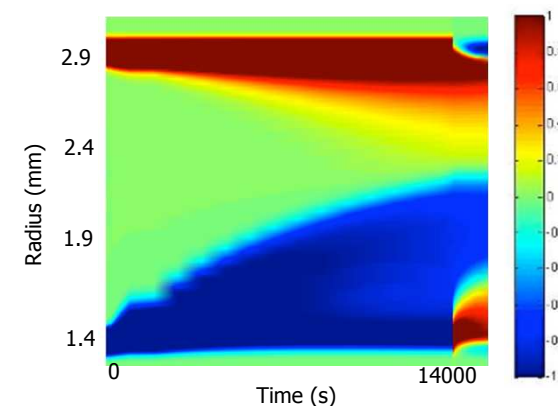
$\Delta T = 0^\circ\text{C}$



$\Delta T = 10^\circ\text{C}$



$\Delta T = 20^\circ\text{C}$





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Conclusions

- Models to help understand the behaviour of a material under electrical stress
- Complementarity of each type of model
- Need to develop the intermediate models with a cylindrical geometry
- Strong effect of temperature gradient on simulated space charge profiles